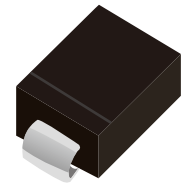


FEATURES

- | Glass Passivated Die Construction
- | Fast Recovery Time for High Efficiency
- | Low reverse leakage
- | Ideally Suited for Automatic Assembly



DO-214AA(SMB)



Schematic Symbol

MECHANICAL DATA

- | Case Material: UL Flammability Classification Rating 94V-0
- | Moisture Sensitivity: Level 1 per J-STD-020

APPROVALS

RoHS	Compliance with 2011/65/EU
HF	Compliance with IEC61249-2-21:2003

MAXIMUM RATINGS AND CHARACTERISTICS (T_A=25°C)

Parameter	Symbol	ES3AB	ES3BB	ES3CB	ES3DB	ES3FB	ES3GB	ES3HB	ES3JB	Unit
Marking		ES3AB	ES3BB	ES3CB	ES3DB	ES3FB	ES3GB	ES3HB	ES3JB	
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	150	200	300	400	500	600	V
Maximum RMS voltage	V _{RMS}	30	70	105	140	210	280	350	420	
Maximum DC blocking voltage	V _{DC}	50	100	150	200	300	400	500	600	
forward current	I _{F(AV)}	3								A
Surge peak forward current,8.3ms single half sine-wave superimposed on rated load per diode	I _{FSM}	100								
Junction-to-lead thermal resistance	R _{θJL}	24								°C/W
Junction-to-ambient thermal resistance	R _{θJA}	84								
Junction-to-case thermal resistance	R _{θJC}	26								
Operating junction and storage temperature range	T _J ,T _{STG}	-55 to +150								°C

ELECTRICAL CHARACTERISTICS($T_A=25^{\circ}\text{C}$)

Parameter		Test Condition	Symbol	Typ.	Max.	Unit
Forward voltage per diode ⁽¹⁾	ES3AB,ES3BB ES3CB,ESSDB	$I_F=1.5\text{A}, T_J=25^{\circ}\text{C}$	V_F	0.80	0.92	V
	ES3FB,ES3GB			0.90	1.04	V
	ES3HB,ES3JB			1.11	1.30	V
	ES3AB,ES3BB ES3CB,ESSDB	$I_F=3.0\text{A}, T_J=25^{\circ}\text{C}$	V_F	0.86	1.00	V
	ES3FB,ES3GB			0.98	1.13	V
	ES3HB,ES3JB			1.24	1.45	V
	ES3AB,ES3BB ES3CB,ESSDB	$I_F=1.5\text{A}, T_J=125^{\circ}\text{C}$	V_F	0.66	0.75	V
	ES3FB,ES3GB			0.73	0.85	V
	ES3HB,ES3JB			0.85	0.98	V
	ES3AB,ES3BB ES3CB,ESSDB	$I_F=3.0\text{A}, T_J=125^{\circ}\text{C}$	V_F	0.73	0.84	V
	ES3FB,ES3GB			0.83	0.95	V
	ES3HB,ES3JB			0.99	1.13	V
Reverse current @ rated V_R per diode ⁽²⁾		$T_J=25^{\circ}\text{C}$	I_R	-	10	μA
		$T_J=125^{\circ}\text{C}$		-	100	μA
Junction capacitance	ES3AB,ES3BB ES3CB,ESSDB	1MHz, $V_R=4.0\text{V}$	C_J	46	-	V
	ES3FB,ES3GB			41	-	V
	ES3HB,ES3JB			34	-	V
Reverse recovery time		$I_F=0.5\text{A}, I_R=1.0\text{A}, I_{RR}=0.25\text{A}$	t_{rr}	-	35	ns

Notes :

1. Pulse test with $PW=0.3\text{ms}$
2. Pulse test with $PW=30\text{ms}$

CHARACTERISTIC CURVES

Fig. 1- Maximum Forward Current Derating Curve

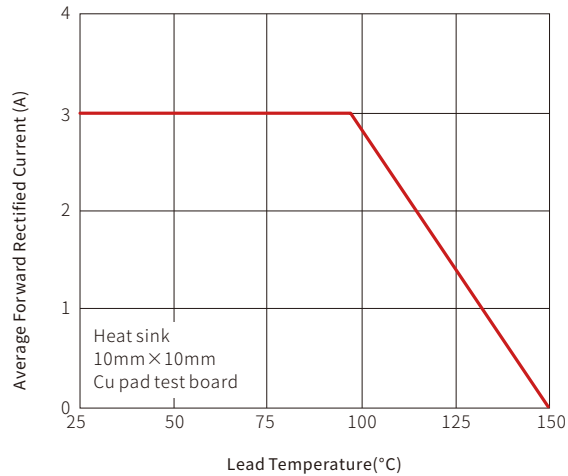


Fig. 2-Typical Junction Capacitance

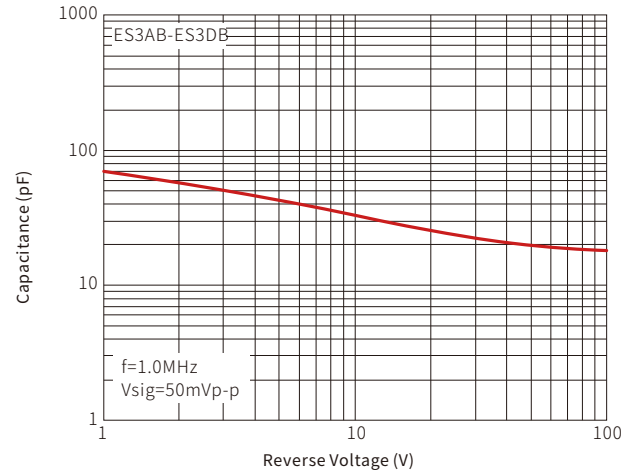


Fig. 3-Typical Reverse Characteristics

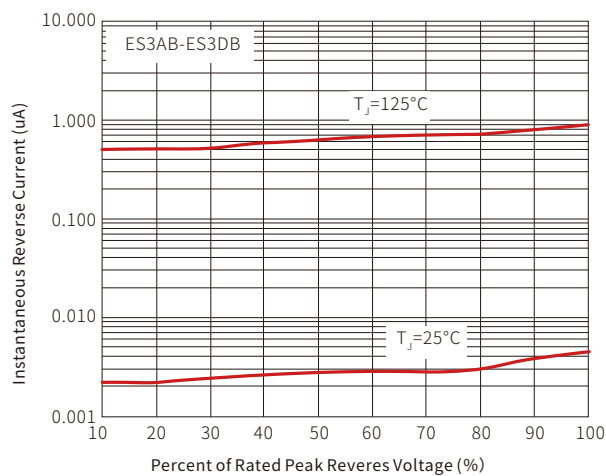


Fig. 4-Typical Forward Characteristics

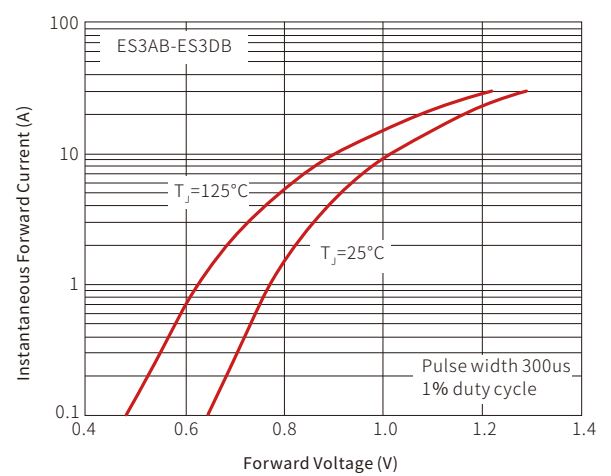


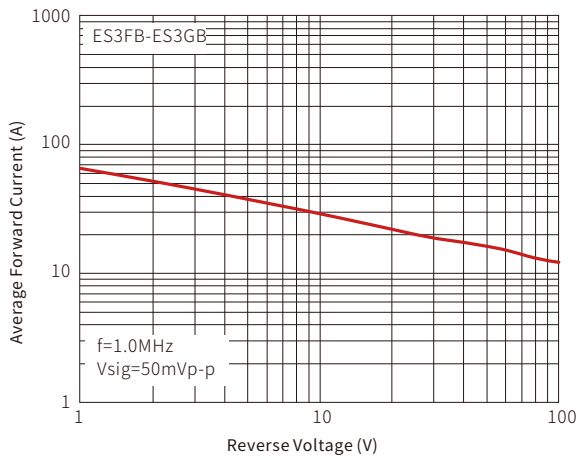
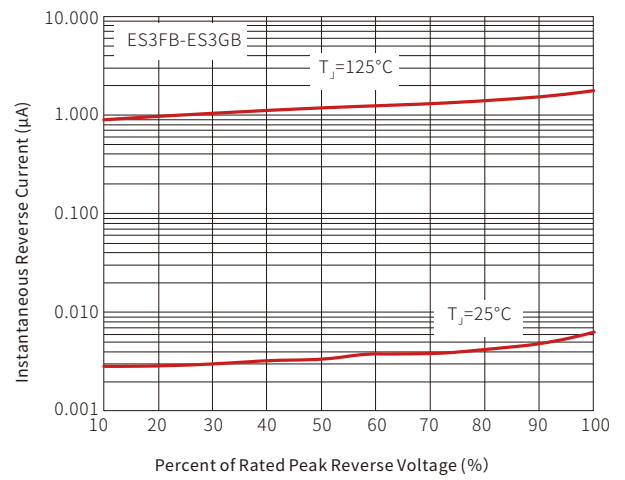
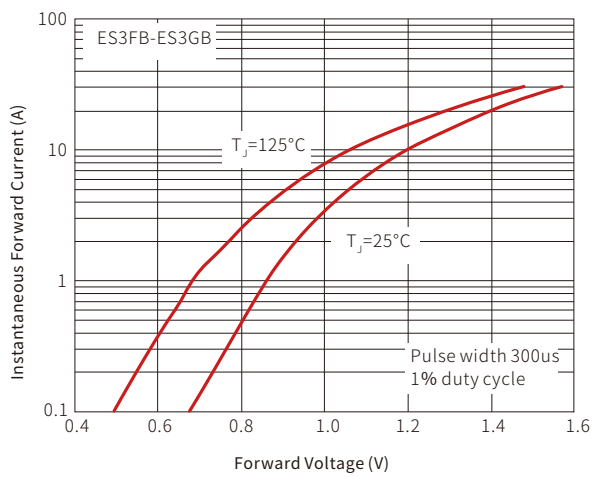
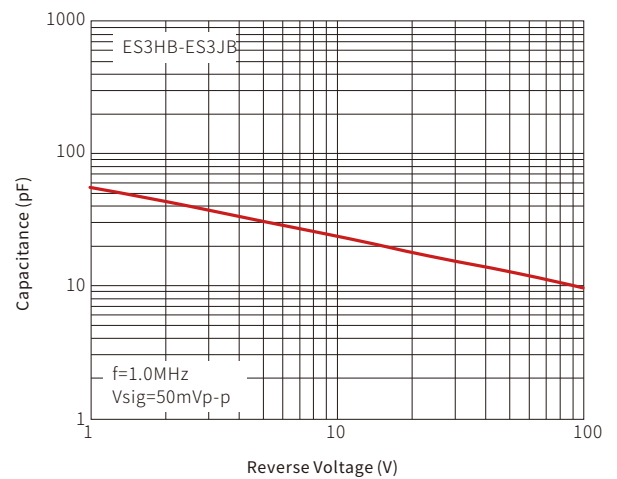
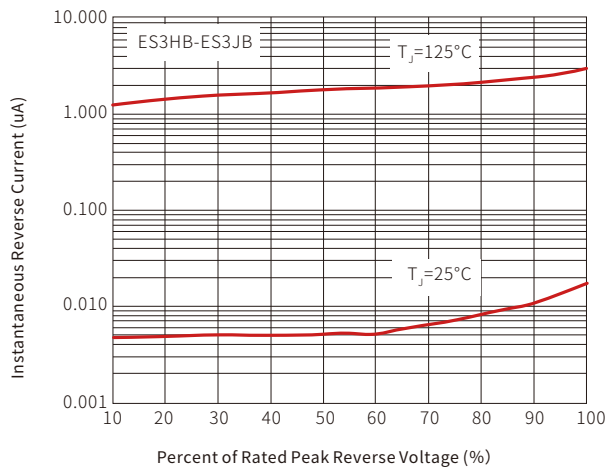
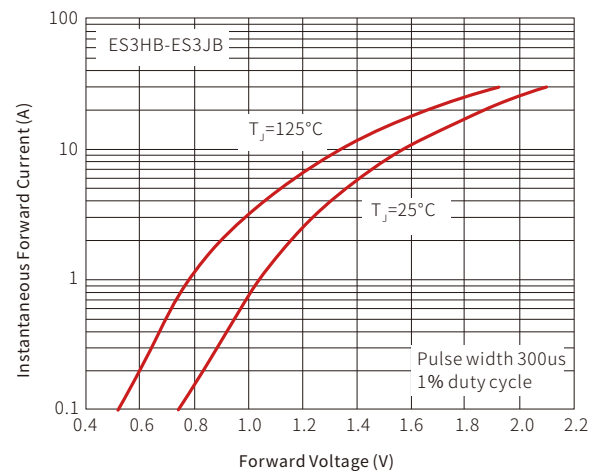
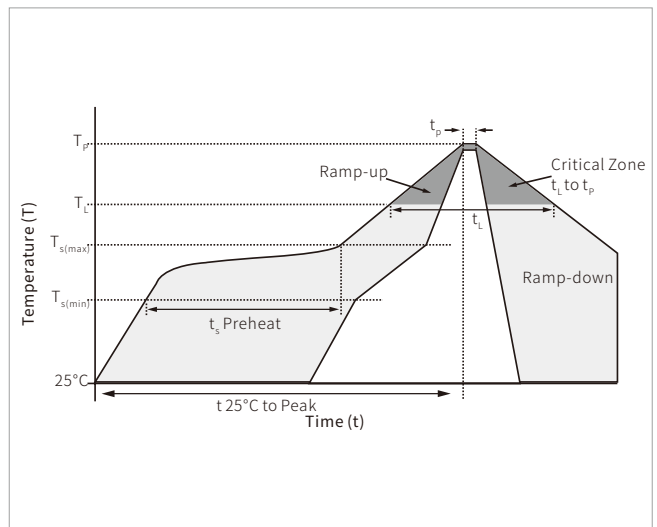
Fig. 5- Typical Junction Capacitance

Fig. 6- Typical Reverse Characteristics

Fig. 7- Typical Forward Characteristics

Fig. 8- Typical Junction Capacitance


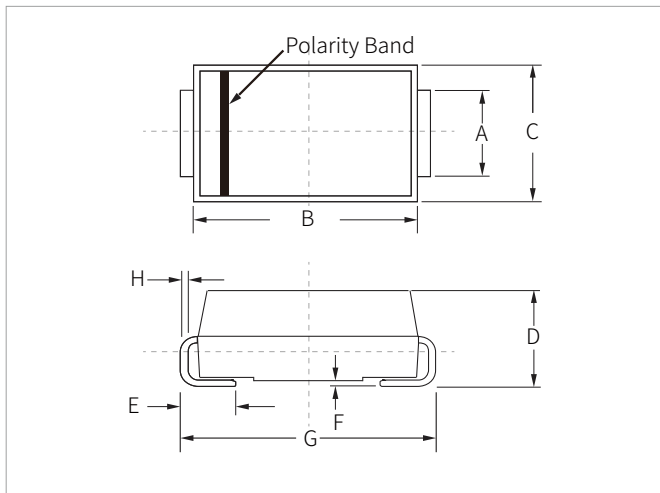
Fig. 9- Typical Reverse Capacitance

Fig. 10- Typical Forward Characteristics


SOLDERING PARAMETERS

Reflow Condition		Lead-free assembly
Pre Heat	Temperature Max ($T_{s(\min)}$)	150°C
	Temperature Max ($T_{s(\max)}$)	200°C
	Time (min to max) (t_s)	60 – 180 secs
Average ramp up rate (Liquidus Temp (T_L) to peak $T_{s(\max)}$ to T_L - Ramp-up Rate)		3°C/second max
Reflow	Temperature (T_L) (Liquidus)	217°C
	Time (min to max) (t_L)	60 – 150 seconds
	Peak Temperature (T_p)	260°C
Time within 5°C of actual peak Temperature (t_p)		20 – 40 seconds
Ramp-down Rate		6°C/second max
Time 25°C to peak Temperature (T_p)		8 minutes max.
Do not exceed		260°C

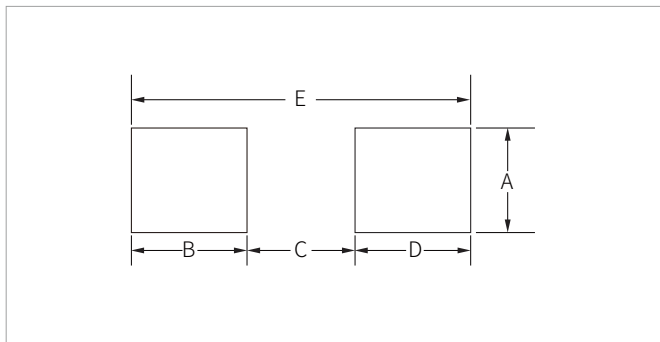


DO-214AA(SMB) PACKAGE INFORMATION



Ref.	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	1.80	2.20	0.071	0.087
B	4.30	4.70	0.170	0.185
C	3.40	3.90	0.134	0.153
D	2.15	2.75	0.085	0.108
E	1.00	1.50	0.039	0.059
F	0.02	0.20	0.001	0.008
G	5.10	5.50	0.200	0.216
H	0.15	0.30	0.006	0.012

RECOMMENDED PAD LAYOUT DIMENSIONS



Ref.	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	2.20	-	0.087	-
B	1.45	-	0.057	-
C	-	2.55	-	0.010
D	1.45	-	0.057	-
E	5.60REF		0.220REF	

ORDERING INFORMATION

Part Number	Component Package	QTY/Reel	Reel Size
ES3AB-ES3JB	DO-214AA(SMB)	3000PCS	13"

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